

AUTOMOTIVE CURRENT TRANSDUCER

HAH1BV S/02



Introduction

The HAH1BV family is for the electronic measurement of DC, AC or pulsed currents in high power automotive applications with galvanic isolation between the primary circuit (high power) and the secondary circuit (electronic circuit).

The HAH1BV family gives you the choice of having different current measuring ranges in the same housing (from ± 200 A up to ± 900 A).

Features

- Open Loop transducer using the Hall effect
- Unipolar + 5 V DC power supply
- Primary current measuring range up to ± 500 A
- Maximum rms primary current limited by the busbar, the magnetic core or the ASIC temperature $T^\circ < + 150^\circ\text{C}$
- Operating temperature range: $- 40^\circ\text{C} < T^\circ < + 125^\circ\text{C}$
- Output voltage: full ratiometric (in sensitivity and offset)
- Compact design.

Advantages

- Excellent accuracy
- Very good linearity
- Very low thermal offset drift
- Very low thermal sensitivity drift
- Wide frequency bandwidth
- No insertion losses.

Automotive applications

- Battery monitoring
- Starter Generators
- Inverters
- HEV application
- EV application.

Principle of HAH1BV Family

The open loop transducers use an Hall effect integrated circuit.

The magnetic flux density **B**, contributing to the rise of the Hall voltage, is generated by the primary current I_p to be measured.

The current to be measured I_p is supplied by a current source i.e. battery or generator (Fig. 1).

Within the linear region of the hysteresis cycle, **B** is proportional to:

$$\mathbf{B} (I_p) = \text{constant} (a) \times I_p$$

The Hall voltage is thus expressed by:

$$V_H = (R_H/d) \times l \times \text{constant} (a) \times I_p$$

Except for I_p , all terms of this equation are constant. Therefore:

$$V_H = \text{constant} (b) \times I_p$$

The measurement signal V_H amplified to supply the user output voltage or current.

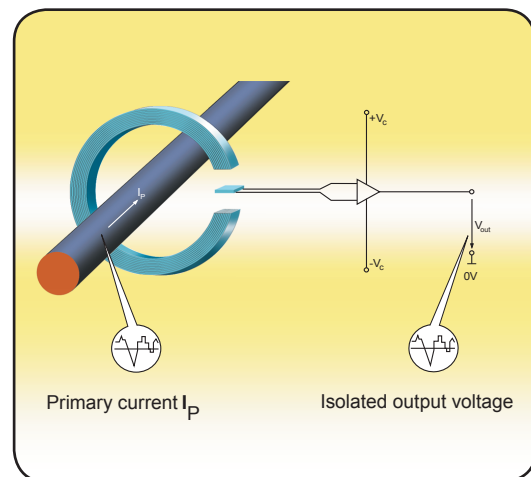
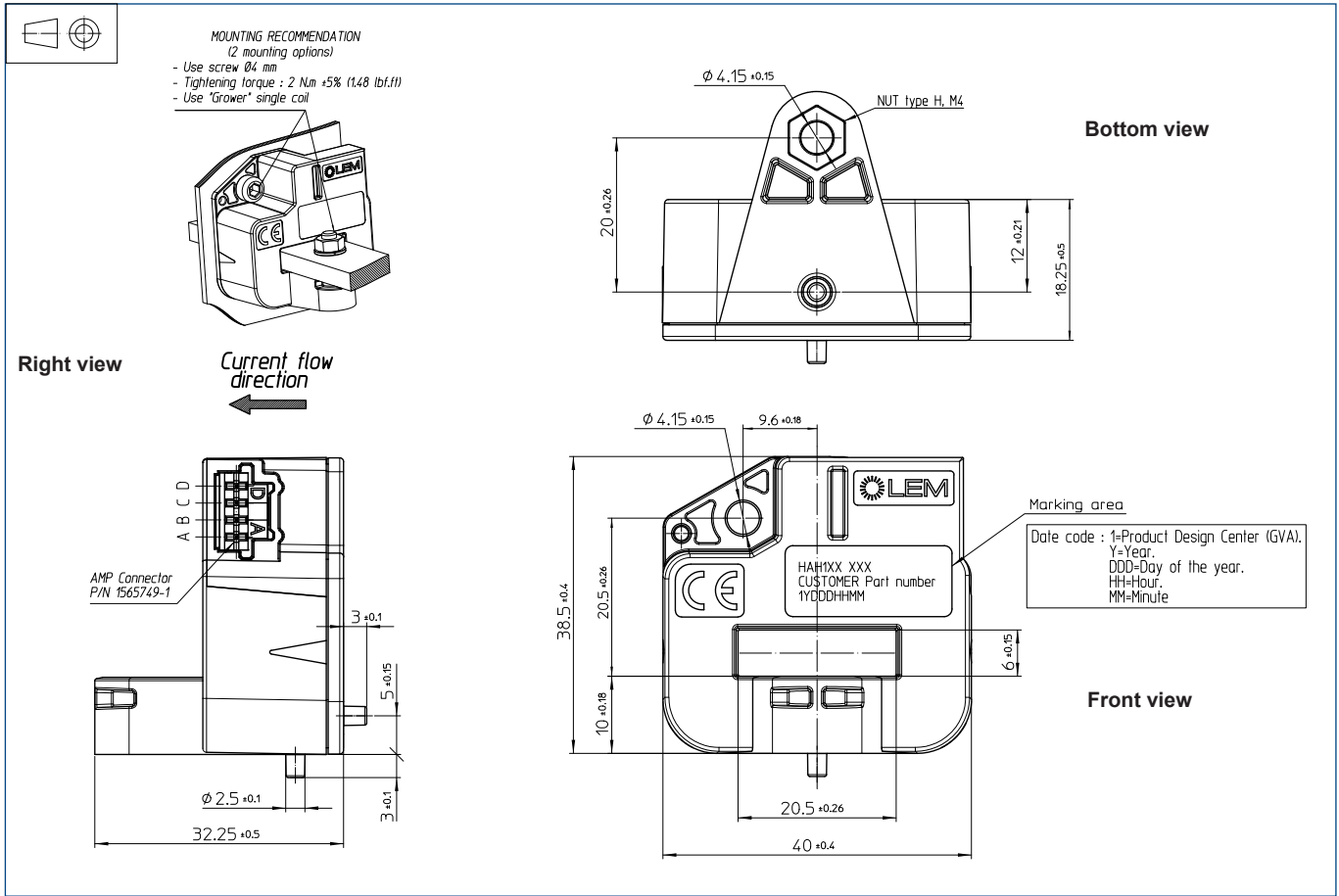


Fig. 1: Principle of the open loop transducer

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Dimensions HAH1BV family (in mm. 1mm = 0.0394 inch)



Bill of materials

- Plastic case PBT GF 30
- Magnetic core Iron silicon alloy
- Pins Brass tin plated
- Mass 39 g

Remarks

- $V_{OUT} > \frac{V_c}{2}$ when I_p flows in the direction of the arrow.

System architecture (example)

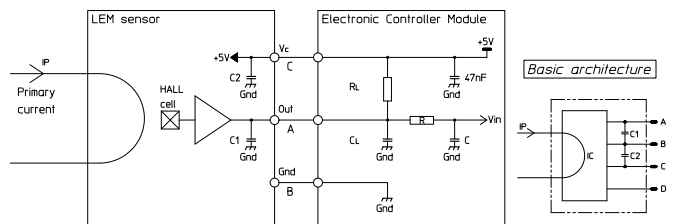
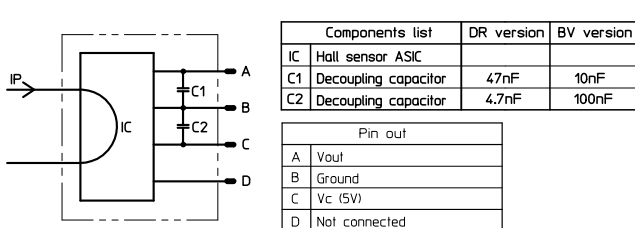
$R_L > 10 \text{ k}\Omega$ optional resistor for signal line diagnostic

| V_{OUT} | Diagnosis |
|--------------|----------------|
| Open circuit | $V_{IN} = V_c$ |
| Short GND | $V_{IN} = 0V$ |

$C_1 < 100 \text{ nF}$ EMC protection

RC Low pass filter EMC protection (optional)

System architecture



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Absolute maximum ratings

| | Symbol | Unit | Specification | | | Conditions |
|-----------------------------------|------------|------|---------------|-----|---------------|----------------------------------|
| | | | Min | Typ | Max | |
| Electrical Data | | | | | | |
| Maximum primary current peak | I_{Pmax} | A | | | ¹⁾ | |
| Supply continuous over voltage | V_C | V | | | 8.5 | |
| Supply over voltage | | | | | 14 | 1 min |
| Reverse voltage | | | -14 | | | 1 min @ $T_A = 25^\circ\text{C}$ |
| Output over voltage (continuous) | V_{OUT} | V | | | 8.5 | |
| Output over voltage | | | | | 14 | 1 min @ $T_A = 25^\circ\text{C}$ |
| Continuous output current | I_{OUT} | mA | -10 | | 10 | |
| Output short-circuit duration | T_C | min | | | 2 | |
| Rms voltage for AC isolation test | V_d | kV | | | 2 | 50 Hz, 1 min |
| Isolation resistance | R_{IS} | MΩ | 500 | | | 500 V - ISO 16750-2 |
| Electrostatic discharge voltage | V_{ESD} | kV | | | 2 | JESD22-A114-B |
| Ambient storage temperature | T_S | °C | -40 | | 125 | |

Operating characteristics

| | Symbol | Unit | Specification | | | Conditions |
|---|-----------------|-------|---|--------|------|--|
| | | | Min | Typ | Max | |
| Electrical Data | | | | | | |
| Primary current | I_P | A | -500 | | 500 | |
| Calibration current | I_{CAL} | A | -500 | | 500 | @ $T_A = 25^\circ\text{C}$ |
| Supply voltage | V_C | V | 4.5 | 5.00 | 5.5 | |
| Output voltage | V_{OUT} | V | $V_{OUT} = (V_C/5) \times (2.5 + G \times I_P)$ | | | @ V_C |
| Sensitivity ²⁾ | G | mV/A | | 4 | | @ $V_C = 5\text{ V}$ |
| Current consumption | I_C | mA | | 7 | 10 | @ $V_C = 5\text{ V}$, -40°C < T_A < 125°C |
| Power up inrush current | | mA | | | 15 | @ $V_C < 3.5\text{ V}$ |
| Load resistance | R_L | KΩ | 10 | | | |
| Output internal resistance | R_{OUT} | Ω | | | 10 | |
| Capacitive loading | C_L | nF | 1 | | 100 | |
| Ambient operating temperature | T_A | °C | -40 | | 125 | |
| Output drift versus power supply | | % | -1 | 0.3 | 1 | |
| Performance Data | | | | | | |
| Sensitivity error | ε_G | % | -1.0 | ± 0.5 | 1.0 | @ $T_A = 25^\circ\text{C}$, '@ $V_C = 5\text{ V}$ |
| Electrical offset current | I_{OE} | A | | ± 1 | | @ $T_A = 25^\circ\text{C}$, '@ $V_C = 5\text{ V}$ |
| Magnetic offset current | I_{OM} | A | | ± 1.2 | | @ $T_A = 25^\circ\text{C}$, '@ $V_C = 5\text{ V}$ after ± I_P |
| Globale offset current | I_O | A | | ± 2.2 | | @ $T_A = 25^\circ\text{C}$ |
| | | | - 3.8 | | 3.8 | |
| Average temperature coefficient of V_{OE} | $TCV_{OE AV}$ | mV/°C | -0.06 | ± 0.02 | 0.06 | @ -40°C < T_A < 125°C |
| Average temperature coefficient of G | TCG_{AV} | %/°C | -0.04 | ± 0.02 | 0.04 | @ -40°C < T_A < 125°C |
| Linearity error | ε_L | % | -1.0 | | 1.0 | of full range |
| Response time to 90 % of I_{PN} step | t_t | ms | | | 5 | @ $di/dt = 50\text{ A}/\mu\text{s}$ |
| Frequency bandwidth | BW | Hz | | | 80 | @ -3 dB |
| Output clamping min voltage | V_{sz} | V | 0.24 | 0.25 | 0.26 | @ $V_C = 5\text{ V}$ |
| Output clamping max voltage | V_{sz} | V | 4.74 | 4.75 | 4.76 | @ $V_C = 5\text{ V}$ |
| Output voltage noise peak peak | $V_{no,pp}$ | mV | - | | 10 | |
| Resolution | | mV | | 2.5 | | @ $V_C = 5\text{ V}$ |
| Power up time | | ms | | 25 | 100 | |
| Setting time after overload | | ms | | | 25 | |

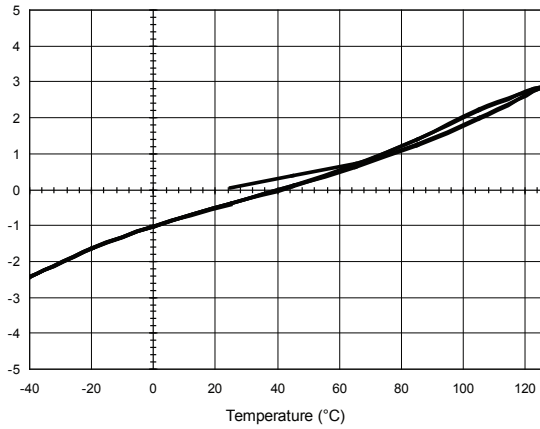
Notes: ¹⁾ Busbar temperature must be below 150°C.

²⁾ The output voltage V_{OUT} is fully ratiometric. The offset and sensitivity are dependent on the supply voltage V_C relative to the following formula:

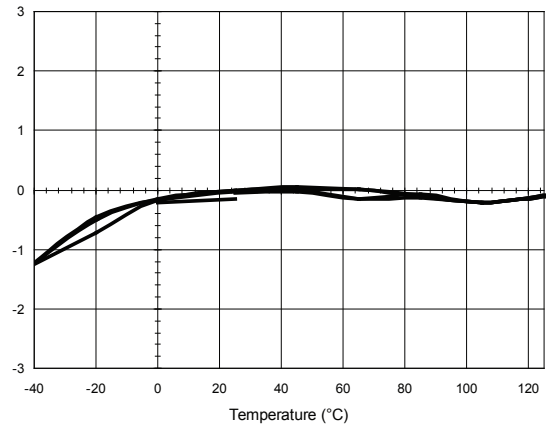
$$I_P = \left(V_{OUT} - \frac{V_C}{2} \right) \times \frac{1}{G} \times \frac{5}{V_C} \quad \text{with } G \text{ in } (V/A)$$

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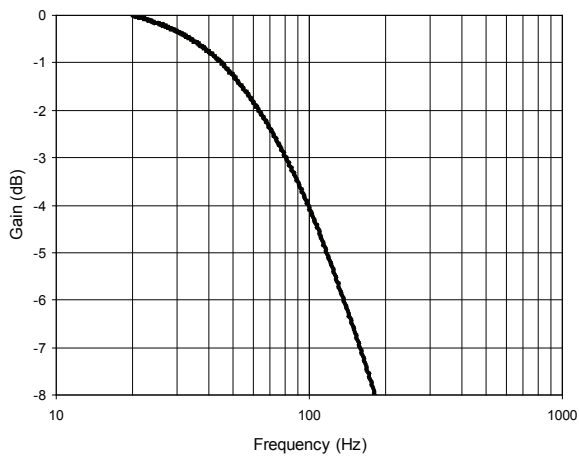
HAH1BV S/02 Gain Error (%)



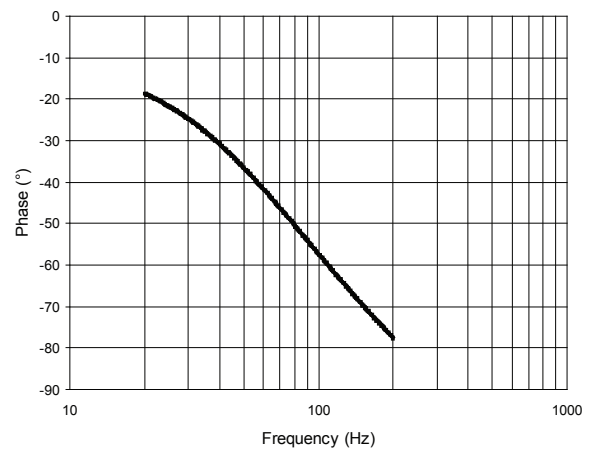
HAH1BV S/02 Electrical offset Error (A)



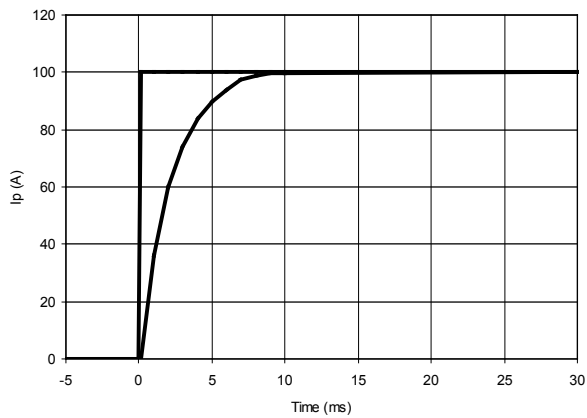
HAH1BV S/02 Frequency Bandwidth



HAH1BV S/02 Phase



Typical Response Time (ms)
di/dt = 100A/us



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PERFORMANCES PARAMETERS DEFINITIONS

Output noise voltage:

The output voltage noise is the result of the noise floor of the Hall elements and the linear I_c amplifier gain.

Magnetic offset:

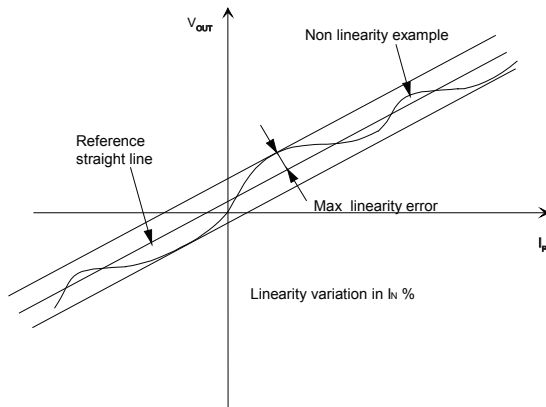
The magnetic offset is the consequence of an over-current on the primary side. It's defined after an excursion of $I_{p\max}$.

Linearity:

The maximum positive or negative discrepancy with a reference straight line $V_{OUT} = f(I_p)$.

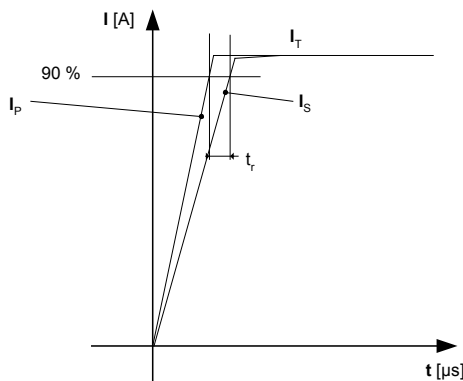
Unit: linearity (%) expressed with full scale of $I_{p\max}$.

Linearity is measured on cycle $+I_p$, 0 , $-I_p$, 0 , $+I_p$ without magnetic offset (average values used)



Response time (delay time) t_r :

The time between the primary current signal and the output signal reach at 90 % of its final value



Typical:

Theoretical value or usual accuracy recorded during the production.

Sensitivity:

The Transducer's sensitivity G is the slope of the straight line

$V_{out} = f(I_p)$, it must establish the relation:

$$V_{out}(I_p) = V_c/5 (G \times I_p + 2.5) (*)$$

(*) For all symetrics transducers.

Offset with temperature:

The error of the offset in the operating temperature is the variation of the offset in the temperature considered with the initial offset at 25°C.

The offset variation I_{OT} is a maximum variation the offset in the temperature range:

$$I_{OT} = I_{OE\max} - I_{OE\min}$$

The Offset drift TCI_{OEAV} is the I_{OT} value divided by the temperature range.

Sensitivity with temperature:

The error of the sensitivity in the operating temperature is the relative variation of sensitivity with the temperature considered with the initial offset at 25°C.

The sensitivity variation G_T is the maximum variation (in ppm or %) of the sensitivity in the temperature range:

$$G_T = (Sensitivity\ max - Sensitivity\ min) / Sensitivity\ at\ 25^\circ C.$$

The sensitivity drift TCG_{AV} is the G_T value divided by the temperature range.

Offset voltage @ $I_p = 0$ A:

Is the output voltage when the primary current is null. The ideal value of V_o is $V_c/2$ at $V_c = 5$ V. So, the difference of $V_o - V_c/2$ is called the total offset voltage error. This offset error can be attributed to the electrical offset (due to the resolution of the ASIC quiescent voltage trimming), the magnetic offset, the thermal drift and the thermal hysteresis.

Environmental test specifications

| Name | Standard | Conditions |
|---|---|---|
| Damp heat, steady state | JESD22-A101 | 85°C - 85°C / 1000h |
| Isolation resistance | ISO 16750-2 § 4.10 | 500 V/1min |
| Temperature humidity cycle test | ISO 16750-4 | -10 + 85°C 10 days |
| Isolation test | IEC 60664-1 | 2 kV/50 Hz/1min |
| Mechanical tests | | |
| Vibration test (random) | IEC 60068-2-64 ISO 16750-3 & 4.1.6.1.6 | 20 ... 2000 Hz Random rms (11g rms) 8h/axis |
| Terminal strength test | According to LEM | |
| Thermal shocks | IEC 60068-214 Na | -40 + 125°C 300 cycles |
| Free fall | ISO 16750-3 § 4.3 | 1m concrete ground |
| EMC Test | | |
| Radiated electromagnetic immunity | Directive 2004/104/CE ISO 11452-2 | 30 V/m 20-2000 MHz |
| Bulk current injection immunity | Directive 2004/104/CE ISO 11452-4 | 1-400 MHz |
| Radiated radio frequency electromagnetic field immunity | IEC 61000-4-3 | 80 MHz to 1,000 MHz - 10 V/m |
| Electrostatic discharge immunity test | IEC 61000-4-2 | Air discharge=2 kV |